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- Voltage-Controlled Oscillator (VCO)
 - Ring Oscillator Using Only One External Biasing Resistor (R_{BIAS})
- Recommended Lock Frequency
 - 100 MHz to 130 MHz
 - $(V_{DD} = 3.3 \text{ V} + 5\%, T_{A} = -20^{\circ}\text{C to } 75^{\circ}\text{C})$
- Phase-Frequency Detector (PFD)
 Includes a High-Speed Edge-Triggered
 Detector With Internal Charge Pump
- Independent VCO, PFD Power-Down Mode
- Thin Small-Outline Package (14 Terminal)
- Compatible Pin Assignment to TLC2932, TLC2933

PW PACKAGE (TOP VIEW) LOGIC V_{DD} □ 14 SELECT ___ 2 \square R_{BIAS} 13 VCO OUT ___ V_{CO IN} 12 ☐ VCO GND FIN-A 11 FIN-B □ 5 10 ☐ VCO INHIBIT PFD OUT □ 6 9 □ PFD INHIBIT 8 TEST LOGIC GND I

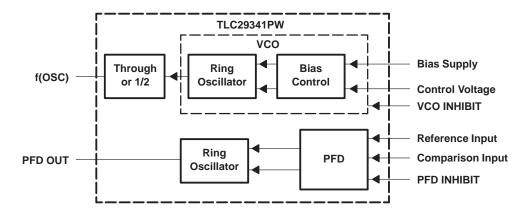
description

The TLC2934, a mixed signal IC designed for phase-locked-loop (PLL) systems, is composed of a voltage-controlled oscillator (VCO) and an edge-triggered-type phase frequency detector (PFD).

The internal VCO is based on the TLC2932 and TLC2933s ring oscillator. It oscillates in wider frequency with lower supply voltage, and it has stable oscillating performance. The oscillation function, provided by only one external resistor connection, supplies bias to the VCI internal circuit. Oscillator range is covered from 10 MHz to 130 MHz with a 3.3-V supply voltage. The VCO has an inhibit function to stop oscillation and for the power-down mode.

The internal PFD, a high-speed rising edge triggered type, has an internal charge pump with a high-impedance output buffer. The PFD detects phase difference between the reference frequency input and the signal frequency input from the VCO output through an external counter device. This functions the same as TLC2932 and TLC2933. The PFD also has the inhibit function for stop phase comparison and for power-down mode.

block diagram





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



Terminal Functions

TERMINAL		.,,	DECORPTION
NAME	NO.	1/0	DESCRIPTION
FIN-A, FIN-B	4 5	I	Frequency signal inputs for PFD. The reference frequency signal (f _{REF-IN}) and the VCO output signal through the external counter device are applied to these terminals. When the LPF design is the lag-lead filter (passive filter and noninverting), f _(REF-IN) is input to FIN-A, and the VCO output signal is to FIN-B.
LOGIC GND	7		GND terminal for the internal logic circuit
LOGIC V _{DD}	1		Power supply terminal for the internal logic circuit. This power supply terminal separates from VCO V_{DD} to reduce cross-coupling between supplies.
PFD INHIBIT	9	ı	PFD INHIBIT (power-down) control signal input terminal
PFD OUT	6	0	PFD output terminal. When PFD INHIBIT is high, PFD OUT is in the high-impedance state.
RBIAS	13	I	Bias resistor (R _{BIAS}) terminal. Connect a resistor between VCO GND and this terminal to supply bias to internal VCO circuit. TLC2934 bias resistor connection is different from TLC2932 and TLC2933, where bias resistor R _{BIAS} is connected to VCO V _{DD} .
SELECT	2	ı	1/2 divider select terminal. L=through output, H=1/2 output.
TEST	8		Test terminal. Use for production test. Tie to GND when in normal use.
VCO GND	11		GND terminal for internal VCO
VCO OUT	3	0	VCO output terminal. When VCO INHIBIT = high, VCO OUT is low.
VCO INHIBIT	10	ı	VCO INHIBIT (power-down) control signal input terminal
VCO IN	12	ı	VCO control voltage input terminal. Normally, The external LPF is connected to this terminal.
VCO V _{DD}	14		Power supply terminal for the internal VCO circuit. This power supply terminal should be separate from LOGIC $V_{\mbox{DD}}$ to reduce cross-coupling between supplies.

absolute maximum ratings over operating free-air temperature (unless otherwise noted)†

Supply voltage (each supply), V _{DD} (see Note 1)	
Input voltage range (each input), V _I (see Note 1)	
Input current (each input), I _I	±20 mA
Output current (each output), IO	±20 mA
Continuous total power dissipation at (or below) T _A = 25°C (see Note 2), P _D	700 mW
Operating free-air temperature range. T _A	–20°C to 75°C
Storage temperature range, T _{stq}	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values are with respect to network ground terminal.
 - 2. For operation above 25°C free—air temperature, derate linearly at the rate of 5.6 mW/°C



recommended operating conditions

		MIN	TYP	MAX	UNIT
Supply voltage (each supply, V _{DD} (3.15	3.3	3.45	V	
Input voltage (each input except for	VCO IN, VI	0		V_{DD}	V
Output current (each output), IO		0		±2	mA
VCO control voltage, V _{CO IN}		0.5		V_{DD}	V
	$R_{BIAS} = 1 k\Omega$	36		130	MHz
Look fraguancy (through output)	$R_{BIAS} = 1.8 \text{ k}\Omega$	28		90	
Lock frequency (through output)	$R_{BIAS} = 2.4 \text{ k}\Omega$	26		80	
	$R_{BIAS} = 3.3 \text{ k}\Omega$	20		60	
	$R_{BIAS} = 1 k\Omega$	18		65	MHz
Lock frequency (1/2 output)	$R_{BIAS} = 1.8 \text{ k}\Omega$	14		45	
Lock frequency (1/2 output)	$R_{BIAS} = 2.4 \text{ k}\Omega$	13		40	
	$R_{BIAS} = 3.3 \text{ k}\Omega$	10		30	
Bias resistor, R _{BIAS}	1.0		3.3	ΚΩ	
Operating temperature range, TA	-20		75	°C	
V _{CO IN} voltage at VCO INHIBIT↓, \	(CINH) (see Note 5)		0	0.5	V

NOTES: 3. It is recommended that the logic supply terminal (LOGIC V_{DD}) and the VCO supply terminal (VCO V_{DD}) be at the same voltage and separated from each other.

- 4. A bypass capacitor is placed as close as possible to each supply terminal.
- $5. \ \ \text{For stable restart of VCO, VCOIN} \ \text{is 0 V when VCO INHIBIT is pulled down to GND level to disable the VCO INHIBIT function.} \ And$ also, VCO IN should be 0 V when the operation will be started by supplying the power.

electrical characteristics over recommended operating free-air temperature range, V_{DD}=3.3 V (unless otherwise noted)

VCO

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Vон	High-level output voltage	$I_{OH} = -2 \text{ mA}$	3.1			V
V _{OL}	Low-level output voltage	I _{OL} = 2 mA			0.2	V
VIH	High-level input voltage	Logic signal input	2.3			V
V _{IL}	Low-level input voltage	Logic signal input			1.0	V
II	Input current at TEST, VCO INHIBIT	$V_I = V_{DD}$ or GND			±1	μΑ
Z _V (CO IN)	Input impedance at V _{COIN}	$V_{COIN} = 1/2 V_{DD}$		10		MΩ
IDD(INH)	VCO supply current (inhibit)	See Note 6		0.01	1	μΑ
I _{DD(VCO)}	VCO supply current	See Note 7		10	15	mA

NOTES: 6. Current into VCO V_{DD}, when VCO INHIBIT = V_{DD}, PFD is inhibited.

7. Current into VCO V_{DD}, when V_{COIN} = 1/2 V_{DD}, R_{BIAS} = 1 k Ω , VCO INHIBIT = GND, PFD is inhibited.



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electrical characteristics over recommended operating free-air temperature range, V_{DD} =3.3 V (unless otherwise noted) (continued)

VCO

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
VOH	High-level output voltage	$I_{OH} = -2 \text{ mA}$	3.1			V
VOL	Low-level output voltage	I _{OL} = 2 mA			0.2	V
IOZ	High-impedance state output current	PFD INHIBIT = high, V _O = V _{DD} or GND			±1	μА
VIH	High-level input voltage at FIN-A,B		2.3			V
VIL	Low-level input voltage at FIN-A,B				1.0	V
V _(TO)	Positive input threshold voltage at PFD INHIBIT		1.0	1.65	2.3	V
Cl	Input capacitance at FIN-A,B			5		pF
Z _(IN)	Input impedance at FIN-A,B			10		ΜΩ
I _{DD(PFD)}	PFD supply current	See Note 8		1.5	6.0	mA

NOTE 8: Current into LOGIC V_{DD} , when FIN-A, FIN-B=50 MHz ($V_{I(pp)}$ = 3.3V, rectangular wave), Test=GND, no load, and VCO OUT is inhibited.

VCO

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
f(OSC)	Operating oscillation frequency	$R_{BIAS} = 1 k\Omega$	67	90	113	MHz
t(STB)	Time to stable oscillation	See Note 9		0.7	10	μs
t _r	Rise time	C _L = 15 pF, See Figure 3		1.7	5	ns
tf	Fall time	C _L = 15 pF, See Figure 3		1.1	4	ns
f(duty)	Duty cycle at VCO OUT	$R_{BIAS} = 1.0 \text{ k}\Omega$, $V_{CO IN} = 1/2 V_{DD}$	45%	50%	55%	
	Temperature coefficient of oscillation frequency	R _{BIAS} =1.0kΩ, $V_{CO\ IN}$ = 1/2 V_{DD} , T_A = -20°C to 75°C		0.03		%/°C
	Supply voltage coefficient of oscillation frequency	R _{BIAS} = 1 kΩ, V _{CO IN} = 1.65 V, V _{DD} = 3.15 V to 3.45 V		0.02		%/mV
	Jitter absolute	$R_{BIAS} = 1 k\Omega$, $V_{CO IN} = 1/2 V_{DD}$		50		ps

NOTE 9: Current into VCO V_{DD} , when VCO INHIBIT = V_{DD} , PFD is inhibited.

PFD AC

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
fMAX	Maximum operating frequency		50			MHz
tPLZ	PFD output disable time from low level	See Figures 4 and 5 and Table 6		15.3	40	ns
tPHZ	PFD output disable time from high level			15.5	40	ns
tPZL	PFD output enable time from low level			2.4	10	ns
tPZH	PFD output enable time from high level			2.5	10	ns
t _r	Rise time	C _L =15 pF (see Figure 3)		1.2	5	ns
t _f	Fall time	C _L =15 pF (see Figure 3)		0.7	5	ns



PARAMETER MEASUREMENT INFORMATION

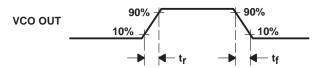
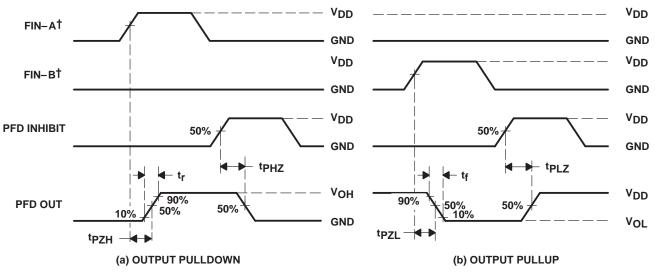


Figure 1. VCO Output Voltage Waveform



(see Figure 3 and PFD Output Test Conditions Table)

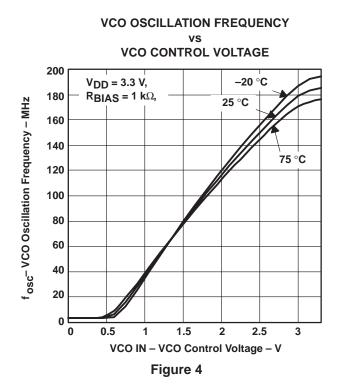
 $\ensuremath{^{\dagger}}$ FIN-A and FIN-B are for reference phase only, not for timing.

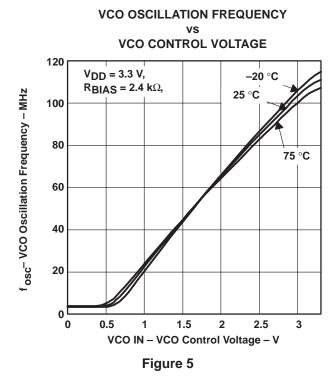
Figure 2. PFD Output Voltage Waveform

PFD	Output	Test Co	nditions		Test Point
PARAMETER	RL	CL	SL	S ₂	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\
^t PZH					S1
^t PHZ			Open	Close	PFD OUT PFD OUT
t _r	1 kΩ	15 55			DUT
tPZL	1 1 1 1 1 1 1	15 pF			\perp \sim \sim S2
tPLZ			Close	Open	↑ cr
t _f					\mathcal{A}

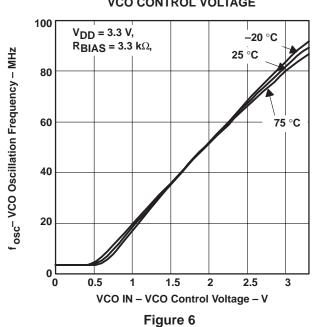
Figure 3. PFD Output Test Condition

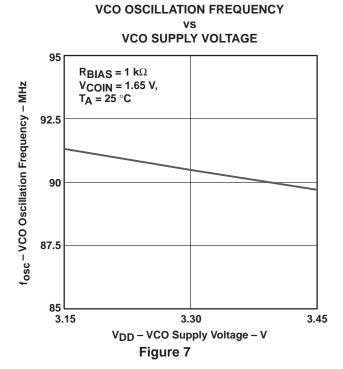
TYPICAL CHARACTERISTICS





VCO OSCILLATION FREQUENCY vs VCO CONTROL VOLTAGE

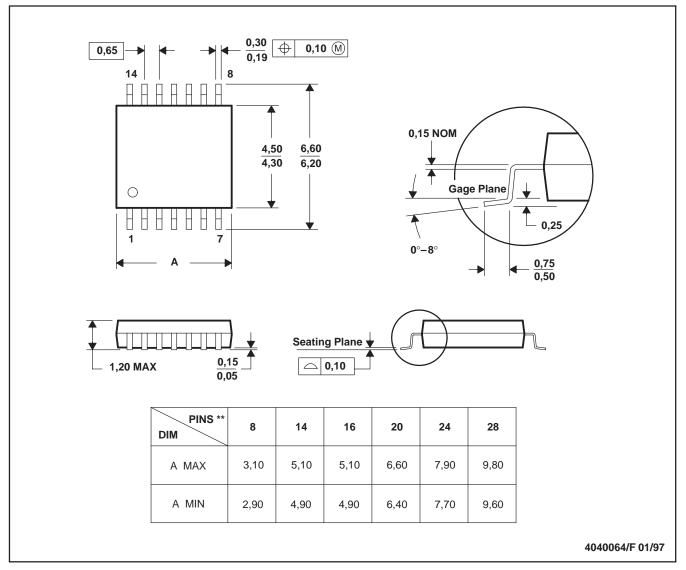




PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153





.com 16-Dec-2006

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TLC2934IPW	NRND	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLC2934IPWG4	NRND	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLC2934IPWR	NRND	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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